Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RJJ0601JPE

Silicon P Channel MOS FET High Speed Power Switching

REJ03G1603-0100 Rev.1.00 Nov 21, 2007

Features

- Low on-resistance $R_{DS(on)} = 8.2 \text{ m}\Omega \text{ typ.}$
- Capable of 4.5 V gate drive
- High speed switching

Outline

RENESAS Package code: PRSS0004AE-B (Package name: LDPAK(S)-(1)) 1. Gate 2. Drain 3. Source 4. Drain

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	-60	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	-90	A
Drain peak current	I _D (pulse) Note1	-360	A
Body-drain diode reverse drain current	I _{DR}	-90	Α
Avalanche current	I _{AP} ^{Note3}	-40	Α
Avalanche energy	E _{AR} Note3	137	mJ
Channel dissipation	Pch ^{Note2}	90	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg \geq 50 Ω

Thermal Impedance Characteristics

• Channel to case thermal impedance θch-c: 1.39°C/W

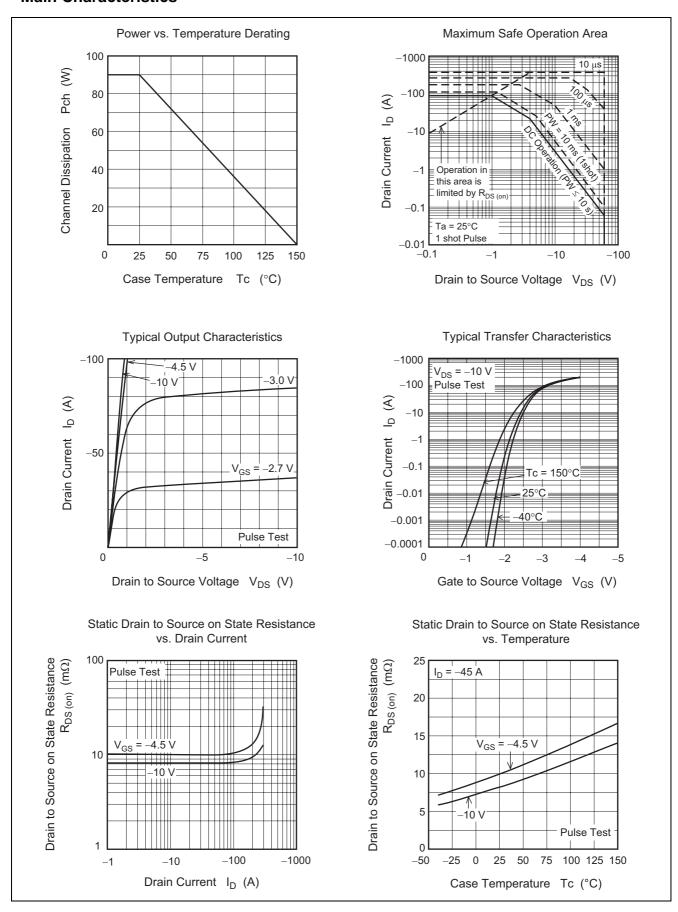
Electrical Characteristics

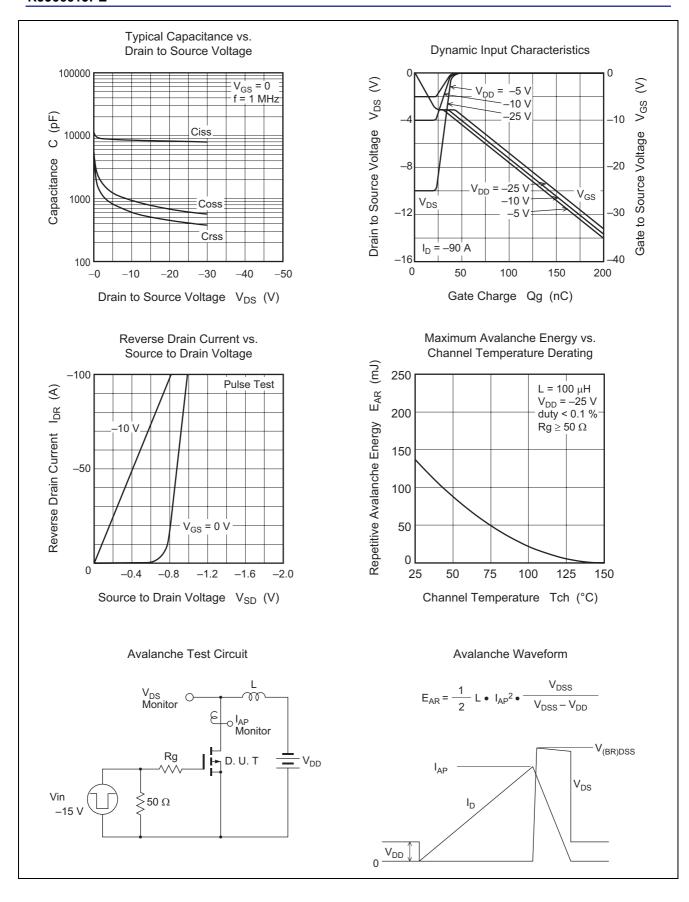
 $(Ta = 25^{\circ}C)$

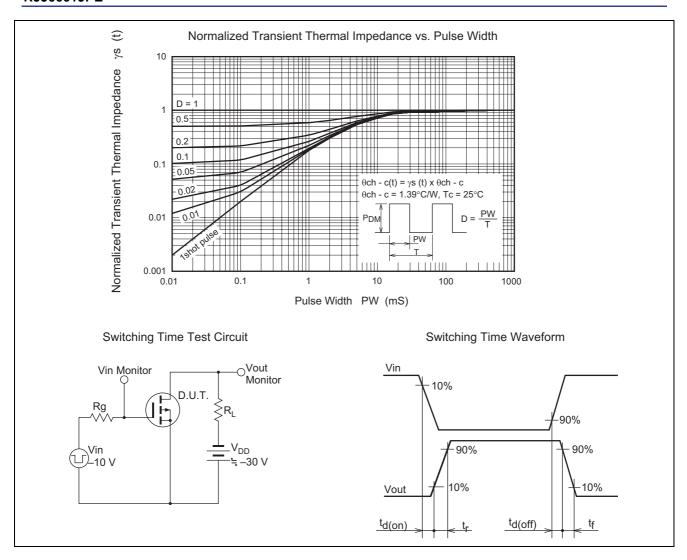
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-10	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	_	-2.5	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}^{Note4}$
Forward transfer admittance	y _{fs}	60	100	_	S	$I_D = -45 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note}4}$
Static drain to source on state	R _{DS(on)}	_	8.2	11	mΩ	$I_D = -45 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note}4}$
resistance	R _{DS(on)}	_	10	15	mΩ	$I_D = -45 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	8800	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0$
Output capacitance	Coss	_	950	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	600	_	pF]
Total gate charge	Qg	_	150	_	nC	$V_{DD} = -25 \text{ V}, V_{GS} = -10 \text{ V},$
Gate to source charge	Qgs	_	25	_	nC	$I_D = -90 \text{ A}$
Gate to drain charge	Qgd	_	23	_	nC]
Turn-on delay time	t _{d(on)}	_	25	_	ns	$V_{GS} = -10 \text{ V}, I_{D} = -45 \text{ A},$
Rise time	t _r	_	30	_	ns	$V_{DD} = -30 V R_G = 4.7 \Omega$
Turn-off delay time	t _{d(off)}		290	_	ns	1
Fall time	t _f	_	135	_	ns]
Body-drain diode forward voltage	V_{DF}	_	-0.96	_	V	$I_F = -90 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	_	45	_	ns	$I_F = -90 \text{ A}, V_{GS} = 0,$ $d_{IF}/dt = 100 \text{ A}/\mu\text{s}$

Note: 4. Pulse test

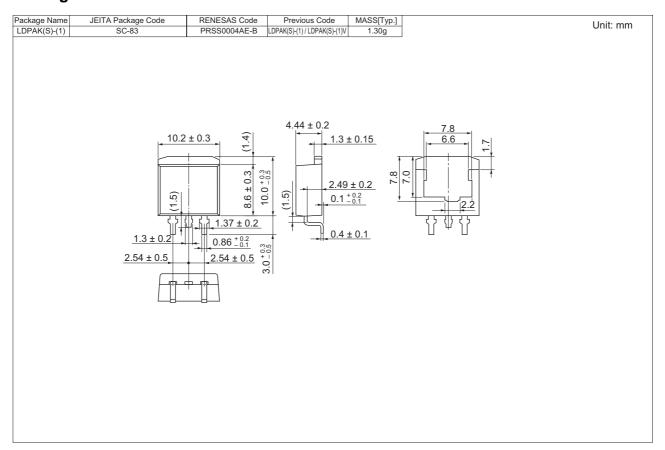
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJJ0601JPE-00-Q3	1000 pcs	Taping (Dextrorse)
RJJ0601JPE-00-J3	1000 pcs	Taping (Sinistrorse)

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